SCLS304A - JANUARY 1996 - REVISED MAY 1997

- **True Logic**
- High-Current 3-State Outputs Can Drive up to 15 LSTTL Loads
- **Package Options Include Plastic** Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

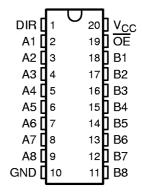
These octal bus transceivers are designed for asynchronous two-way communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending upon the level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

The SN54HC645 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HC645 is characterized for operation from -40°C to 85°C.

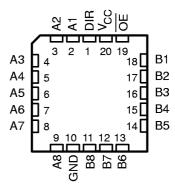
FUNCTION TABLE

INP	UTS	ODEDATION
Œ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

SN54HC645...JORWPACKAGE SN74HC645 . . . DW OR N PACKAGE (TOP VIEW)



SN54HC645...FK PACKAGE (TOP VIEW)

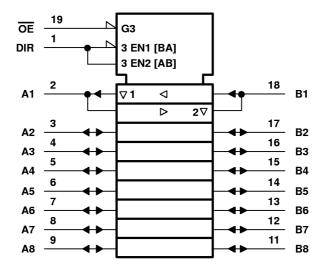




Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

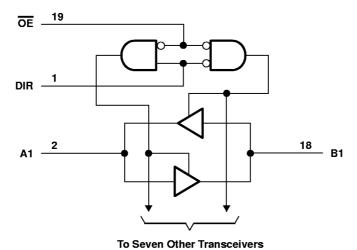


logic symbol†



 $[\]ensuremath{^{\dagger}}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





SCLS304A - JANUARY 1996 - REVISED MAY 1997

absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see Note 1)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) (see Note 1)	
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Package thermal impedance, θ _{JA} (see Note 2): DW package	
N package	
Storage temperature range, T _{sto}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

			SI	SN54HC645		SN74HC645			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		2	5	6	2	5	6	٧
		V _{CC} = 2 V	1.5			1.5			
v_{IH}	High-level input voltage	$V_{CC} = 4.5 \text{ V}$	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
	Low-level input voltage	V _{CC} = 2 V	0		0.5	0		0.5	
V_{IL}		$V_{CC} = 4.5 \text{ V}$	0		1.35	0		1.35	V
		V _{CC} = 6 V	0		1.8	0		1.8	
V _I	Input voltage		0		νcc	0		٧cc	V
٧o	Output voltage		0		vcc	0		٧cc	٧
		V _{CC} = 2 V	0		1000	0		1000	
tţ	Input transition (rise and fall) time	V _{CC} = 4.5 V	0		500	0		500	ns
		V _{CC} = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55	-	125	-40		85	°C



^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

SN54HC645, SN74HC645 OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCLS304A - JANUARY 1996 - REVISED MAY 1997

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAD	AMETED	TEST CONDITIONS		Vac	Т	A = 25°C	;	SN54HC645		SN74HC645		UNIT
PARAMETER		TEST CONDITIONS		Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
				2 V	1.9	1.998		1.9		1.9		
			I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
Voн		$V_I = V_{IH} \text{ or } V_{IL}$		6 V	5.9	5.999		5.9		5.9		V
			I _{OH} = -6 mA	4.5 V	3.98	4.3		3.7		3.84		
			$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
		VI = VIH or VIL	I _{OL} = 20 μA	2 V		0.002	0.1		0.1		0.1	
				4.5 V		0.001	0.1		0.1		0.1	
VOL				6 V		0.001	0.1		0.1		0.1	٧
			$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
			$I_{OL} = 7.8 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
lį	DIR or OE	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
loz	A or B	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ
ICC		$V_I = V_{CC}$ or 0,	I _O = 0	6 V			8		160		80	μΑ
Ci	DIR or OE			2 V to 6 V		3	10	·	10		10	pF

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	то		T _A = 25°C			C645	SN74HC645		UNIT		
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT		
			2 V		40	105		160		130			
^t pd	A or B	B or A	4.5 V		15	21		32		26	ns		
			6 V		12	18		27		22			
	ŌĒ	A or B	2 V		125	230		340		290			
t _{en}			4.5 V		23	46		68		58	ns		
					6 V		20	39		58		49	
	ŌĒ		2 V		74	200		300		250			
^t dis		ŌĒ	A or B	A or B	4.5 V		25	40		60		50	ns
					6 V		21	34		51		43	
		A or B	2 V		20	60		90		75			
tţ			A or B	4.5 V		8	12		18		15	ns	
			6 V		6	10		15		13			



SN54HC645, SN74HC645 **OCTAL BUS TRÁNSCEIVERS** WITH 3-STATE OUTPUTS SCLS304A – JANUARY 1996 – REVISED MAY 1997

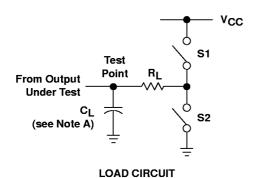
switching characteristics over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V	T	_ = 25°C	;	SN54H	IC645	SN74H	C645	UNIT																
PARAWETER	(INPUT)		Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT																
			2 V		54	135		200		170																	
^t pd	A or B	B or A	4.5 V		18	27		40		34	ns																
																			6 V		15	23		34		29	
				2 V		150	270		405		335																
t _{en}	ŌĒ	A or B	4.5 V		31	54		81		67	ns																
			6 V		25	46		69		56																	
			2 V		45	210		315		265																	
t _t		A or B	4.5 V		17	42		63		53	ns																
			6 V		13	36		53		45																	

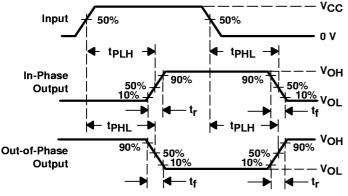
operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per transceiver	No load	40	pF

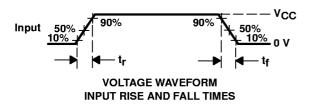
PARAMETER MEASUREMENT INFORMATION

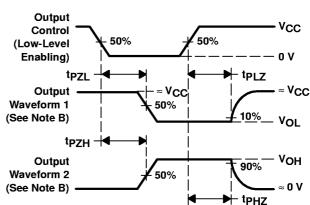


PARAI	PARAMETER		CL	S1	S2	
	^t PZH	1 kΩ	50 pF or	Open	Closed	
t _{en}	^t PZL	1 K52	150 pF	Closed	Open	
1	^t PHZ	1 kΩ	50 pF	Open	Closed	
^t dis	^t PLZ	1 K32	30 pr	Closed	Open	
t _{pd} or	tį		50 pF or 150 pF	Open	Open	



VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES





VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- NOTES: A. C_I includes probe and test-fixture capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r = 6 \text{ ns}$, $t_f = 6 \text{ ns}$.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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